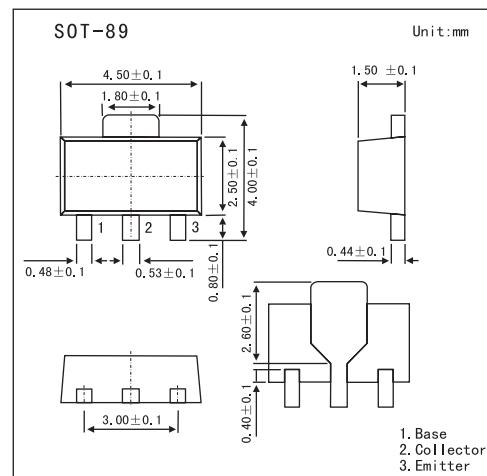


NPN Epitaxial Planar Silicon Transistor**2SD1628****■ Features**

- Low saturation voltage.
- High hFE.
- Large current capacity.
- Very small size making it easy to provide high density, small-sized hybrid IC's.

■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	60	V
Collector-emitter voltage	V _{C EO}	20	V
Emitter-base voltage	V _{EBO}	6	V
Collector current	I _C	5	A
Collector current (pulse)	I _{CP}	8	A
Collector dissipation	P _C	500	mW
	P _C *	1.5	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

* Mounted on ceramic board(250mm²×0.8mm)

2SD1628■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			100	nA
Emitter cutoff current	I_{EBO}	$V_{EB} = 5 \text{ V}, I_C = 0$			100	nA
DC current gain	h_{FE}	$V_{CE} = 2 \text{ V}, I_C = 0.5 \text{ A}$	120		560	
Gain bandwidth product	f_T	$V_{CE} = 10 \text{ V}, I_C = 50 \text{ mA}$		120		MHz
Output capacitance	C_{ob}	$V_{CB} = 10 \text{ V}, f = 1.0 \text{MHz}$		45		pF
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 3 \text{ A}, I_B = 60 \text{ mA}$			500	mV
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 3 \text{ A}, I_B = 60 \text{ mA}$			1.5	V
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 10 \mu\text{A}, I_E = 0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1 \text{mA}, R_{BE} = \infty$	20			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 10 \mu\text{A}, I_C = 0$	6			V
Turn-on timie	t_{on}	Switching Time Test Circuit $t_{ON} = 10 \mu\text{s}$ $t_{OFF} = 2 \mu\text{s}$ $t_R = t_F = 2 \mu\text{s}$ $t_{SG} = 7 \mu\text{s}$ $R_E = 10 \text{ k}\Omega$ $R_L = 100 \text{ }\Omega$ $C_L = 0.01 \mu\text{F}$ $V_{BE(on)} = -0.02 \text{V}$ $I_C = 2 \text{A}$ $t_{ON} = t_R + t_F + t_{SG}$ $t_{OFF} = t_R + t_F + t_{SG} + t_{OFF}$		30		ns
Storage time	t_{stg}			300		ns
Turn-off time	t_f			40		ns

■ hFE Classification

Marking	DK		
Rank	E	F	G
hFE	120~200	160~320	280~560